80 V, 1 A PNP medium power transistors Rev. 9 — 19 October 2011

1. **Product profile**

1.1 General description

PNP medium power transistor series in Surface-Mounted Device (SMD) plastic packages.

Product overview Table 1.

Type number ^[1]	Package	NPN complement		
	NXP	JEITA	JEDEC	
BCP53	SOT223	SC-73	-	BCP56
BCX53	SOT89	SC-62	TO-243	BCX56
BC53PA	SOT1061	-	-	BC56PA

[1] Valid for all available selection groups.

1.2 Features and benefits

- High current
- Three current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity (SOT89, SOT1061)
- Leadless very small SMD plastic package with medium power capability (SOT1061)
- AEC-Q101 gualified

1.3 Applications

- Linear voltage regulators
- High-side switches
- Battery-driven devices
- Power management
- MOSFET drivers
- Amplifiers

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-80	V
I _C	collector current		-	-	-1	А
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	-2	А



80 V, 1 A PNP medium power transistors

Table 2.	e 2. Quick reference data continued					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
h _{FE}	DC current gain	$V_{CE} = -2 V;$ $I_{C} = -150 \text{ mA}$	63	-	250	
	h _{FE} selection -10	$V_{CE} = -2 V;$ $I_{C} = -150 mA$	63	-	160	
	h _{FE} selection -16	$V_{CE} = -2 V;$ $I_{C} = -150 \text{ mA}$	100	-	250	

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
SOT223			
1	base		
2	collector		2, 4
3	emitter		1
4	collector		3 sym028
SOT89			
1	emitter	_	
2	collector		2
3	base		3
SOT1061			000aaa231
1	base		
2	emitter	3	3
3	collector		
		1 2 Transparent top view	sym013

80 V, 1 A PNP medium power transistors

3. Ordering information

Table 4. Ordering information					
Type number ^[1]	Package				
	Name	Description	Version		
BCP53	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223		
BCX53	SC-62	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89		
BC53PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body $2 \times 2 \times 0.65$ mm	SOT1061		

[1] Valid for all available selection groups.

4. Marking

Table 5. Marking codes	
Type number	Marking code
BCP53	BCP53
BCP53-10	BCP53/10
BCP53-16	BCP53/16
BCX53	АН
BCX53-10	AK
BCX53-16	AL
BC53PA	BV
BC53-10PA	BW
BC53-16PA	BX

80 V, 1 A PNP medium power transistors

5. Limiting values

Table 6. In accorda	Limiting values nce with the Absolute Maximur	n Rating System (IEC	C 60134).		
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	-100	V
V _{CEO}	collector-emitter voltage	open base	-	-80	V
V _{EBO}	emitter-base voltage	open collector	-	-5	V
I _C	collector current		-	-1	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-2	A
I _B	base current		-	-0.3	А
I _{BM}	peak base current	single pulse; $t_p \leq 1 ms$	-	-0.3	A
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	BCP53		<u>[1]</u> _	0.65	W
			[2]	1.00	W
			[3]	1.35	W
	BCX53		<u>[1]</u> _	0.50	W
			[2]	0.95	W
			[3]	1.35	W
	BC53PA		<u>[1]</u> _	0.42	W
			[2]	0.83	W
			[3]	1.10	W
			<u>[4]</u>	0.81	W
			[5]	1.65	W
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

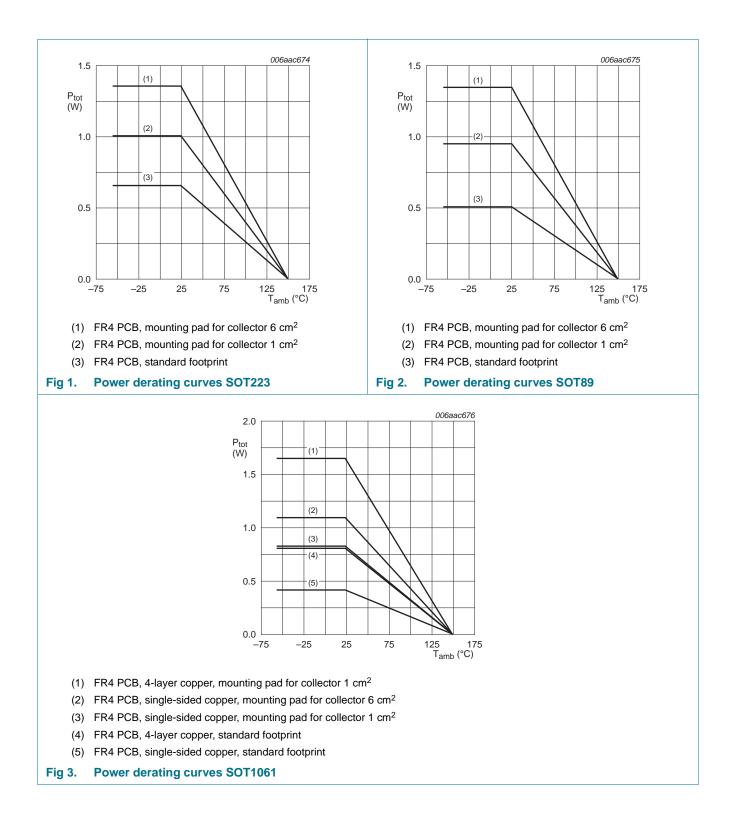
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².

BCP53; BCX53; BC53PA

80 V, 1 A PNP medium power transistors



80 V, 1 A PNP medium power transistors

6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	BCP53		<u>[1]</u> -	-	192	K/W
			[2] _	-	125	K/W
			[3]	-	93	K/W
	BCX53		<u>[1]</u> -	-	250	K/W
			[2] _	-	132	K/W
			[3] _	-	93	K/W
	BC53PA		<u>[1]</u> -	-	298	K/W
			[2] _	-	151	K/W
			[3] _	-	114	K/W
			<u>[4]</u> _	-	154	K/W
			[5]	-	76	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point					
	BCP53		-	-	16	K/W
	BCX53		-	-	16	K/W
	BC53PA		-	-	20	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

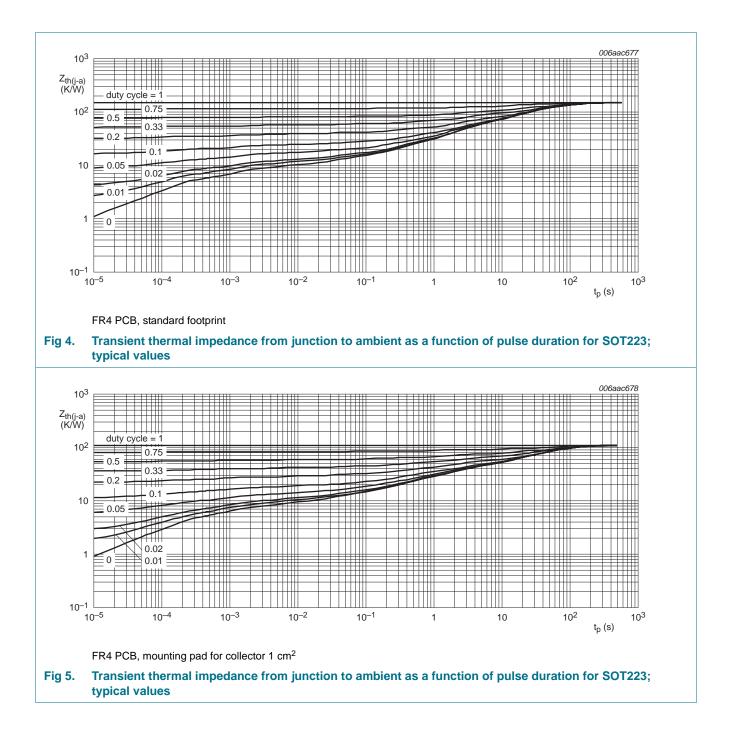
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

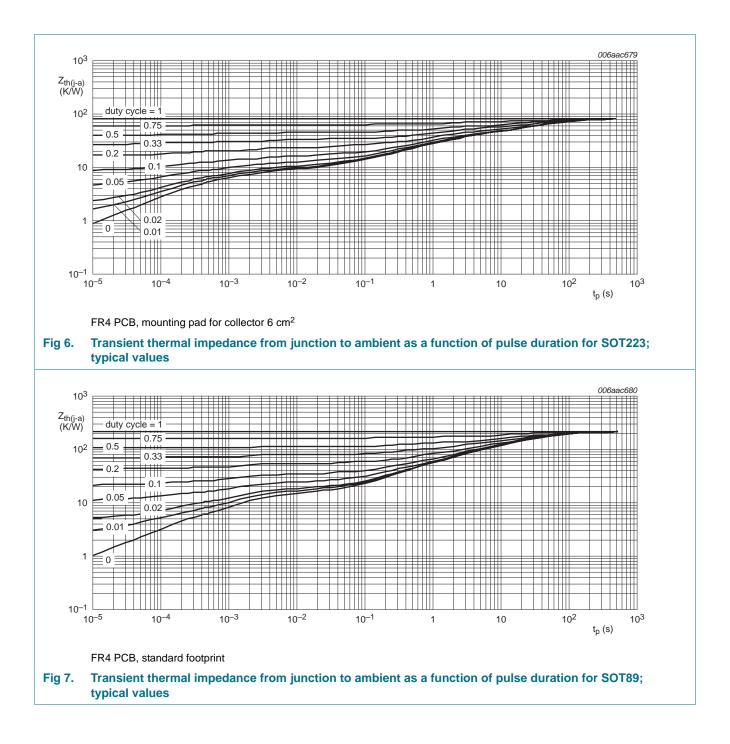
[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².

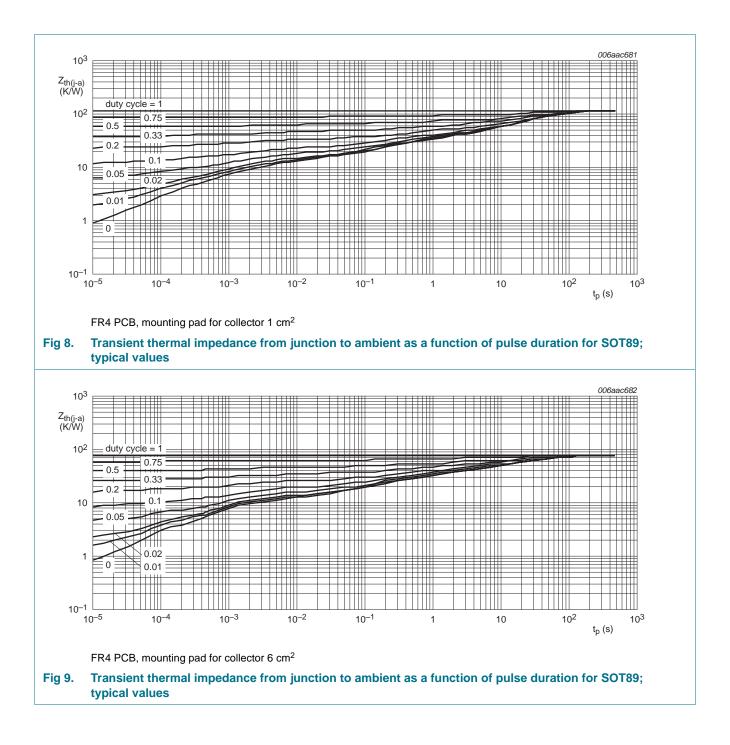
BCP53; BCX53; BC53PA



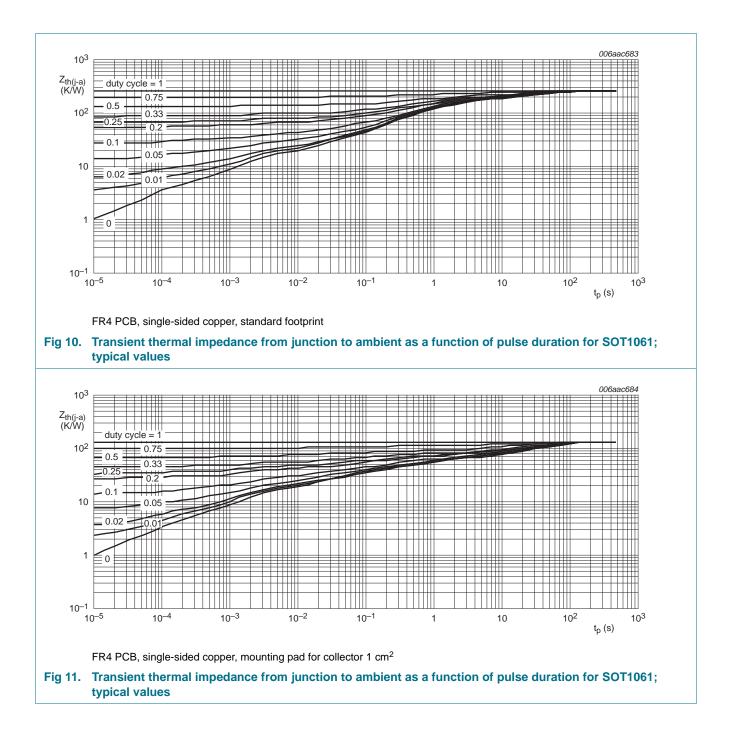
BCP53; BCX53; BC53PA



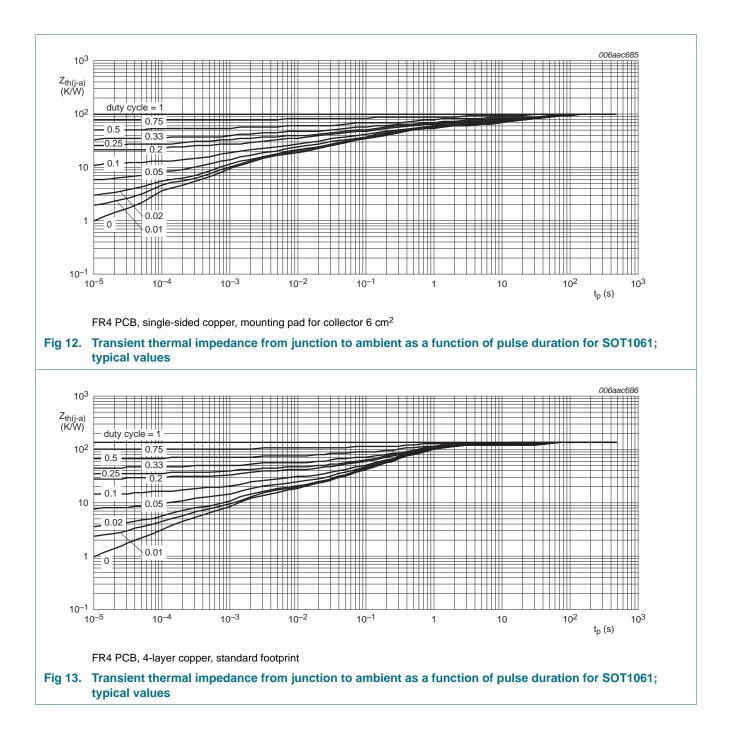
BCP53; BCX53; BC53PA



BCP53; BCX53; BC53PA

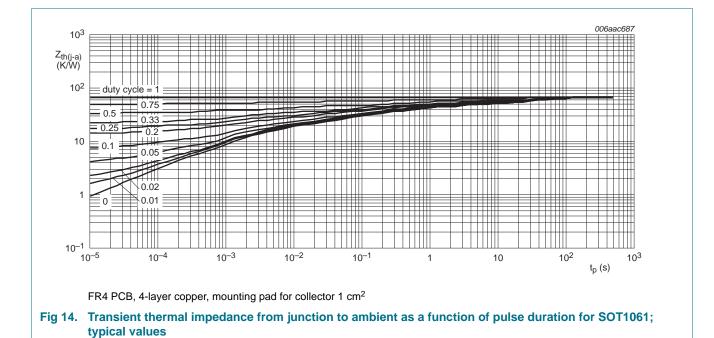


BCP53; BCX53; BC53PA



BCP53; BCX53; BC53PA

80 V, 1 A PNP medium power transistors



7. Characteristics

Table 8.Characteristics

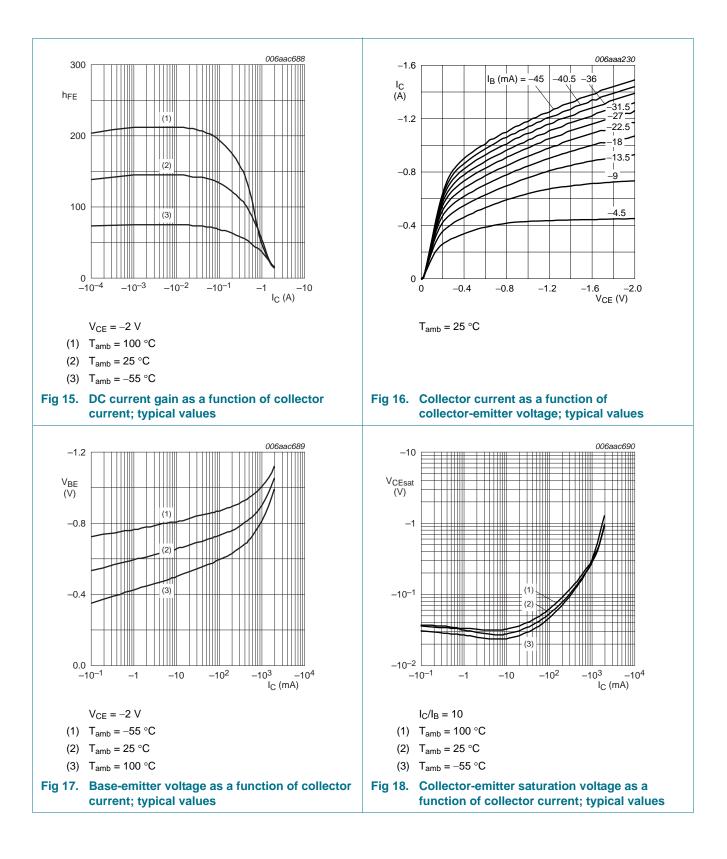
 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO} collector-base cut-off	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}$		-	-	-100	nA	
	current	$\label{eq:VCB} \begin{array}{l} V_{CB} = -30 \text{ V}; \text{ I}_{E} = 0 \text{ A}; \\ T_{j} = 150 \ ^{\circ}\text{C} \end{array}$		-	-	-10	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -2 V$					
		$I_C = -5 \text{ mA}$		63	-	-	
		I _C = -150 mA		63	-	250	
		I _C = -500 mA	[1]	40	-	-	
	DC current gain	$V_{CE} = -2 V$					
	h _{FE} selection -10	I _C = -150 mA		63	-	160	
	h _{FE} selection -16	I _C = -150 mA		100	-	250	
V _{CEsat}	collector-emitter saturation voltage	I _C = -500 mA; I _B = -50 mA	[1]	-	-	-0.5	V
V _{BE}	base-emitter voltage	$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -500 \text{ mA}$	[1]	-	-	-1	V
C _c	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB}=-10 \text{ V}; \text{ I}_{E}=\text{i}_{e}=0 \text{ A};\\ \text{ f}=1 \text{ MHz} \end{array}$		-	15	-	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_C = -50 \text{ mA};$ f = 100 MHz		-	145	-	MHz

[1] Pulse test: $t_p \le 300 \ \mu$ s; $\delta = 0.02$.

BCP53; BCX53; BC53PA

80 V, 1 A PNP medium power transistors



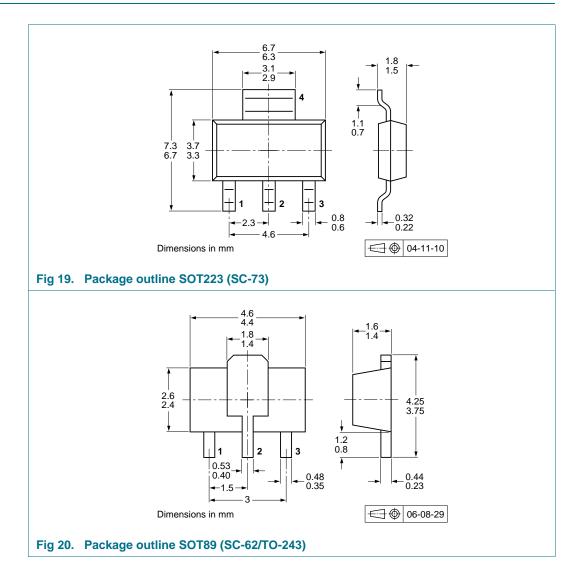
80 V, 1 A PNP medium power transistors

8. Test information

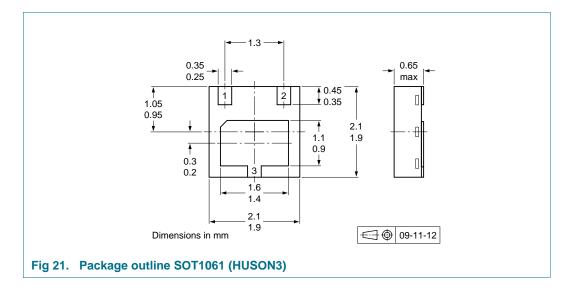
8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



80 V, 1 A PNP medium power transistors



10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Туре	Package	Description		Packir	ng quant	ity
number ^[2]				1000	3000	4000
BCP53	SOT223	8 mm pitch, 12 mm tape and reel		-115	-	-135
BCX53	SOT89	8 mm pitch, 12 mm tape and reel; T1	[3]	-115	-	-135
		8 mm pitch, 12 mm tape and reel; T3	[4]	-146	-	-
BC53PA	SOT1061	4 mm pitch, 8 mm tape and reel		-	-115	-

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

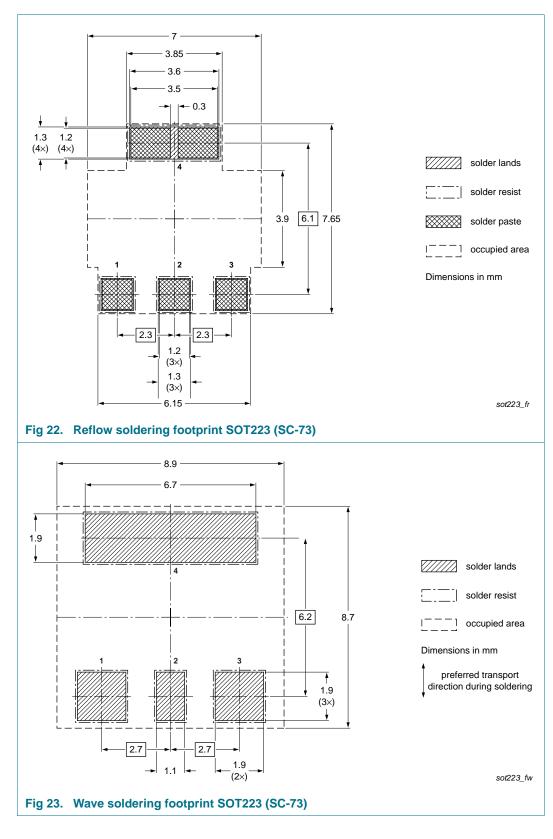
[2] Valid for all available selection groups.

[3] T1: normal taping

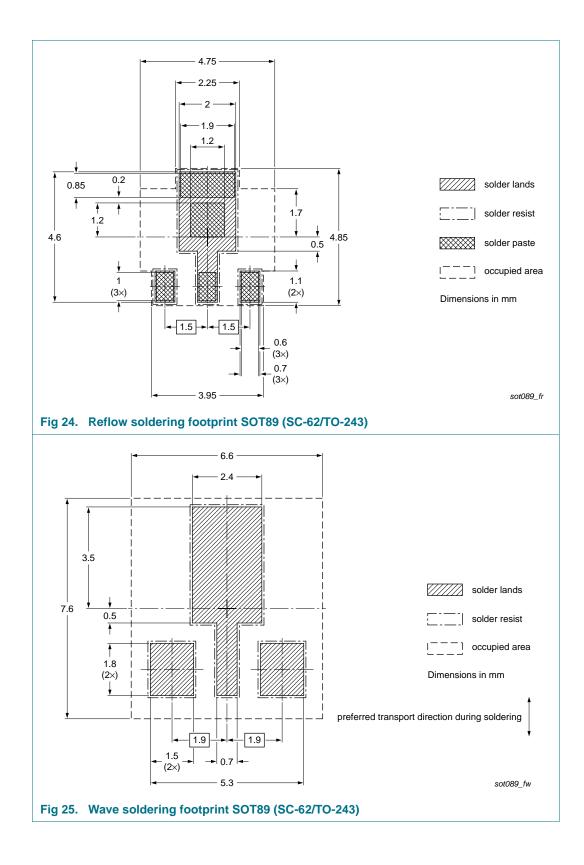
[4] T3: 90° rotated taping

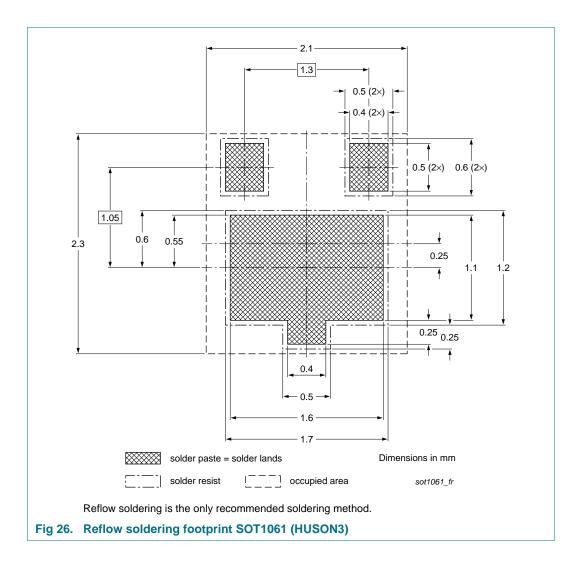
80 V, 1 A PNP medium power transistors

11. Soldering



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80 V, 1 A PNP medium power transistors

12. Revision history

Table 10.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BCP53_BCX53_BC53PA v.9	20111019	Product data sheet	-	BCP640_BCX53_BCX53 v.8
Modifications:	 Type numb 	er removed: BC640		
	 Type numb 	ers added: BC53PA, BC5	3-10PA and BC53-	16PA
	Section 1 "I	Product profile": updated		
	• <u>Table 6, 7</u> a	and 8: updated according	to latest measurem	ents
	• Figure 1, 2,	, <u>4</u> , <u>5</u> , <u>7</u> , <u>8</u> , <u>9</u> , <u>15</u> , <u>17</u> and <u>5</u>	18 : updated	
	 Figure 3, 6, 	, <u>10</u> to <u>14</u> : added		
	Section 8 "	Test information": added		
	Section 10	"Packing information": up	dated	
	Section 11	"Soldering": added		
	Section 13	"Legal information": upda	ted	
BCP640_BCX53_BCX53 v.8	20080222	Product data sheet	-	BC640_BCP53_BCX53 v.7
BC640_BCP53_BCX53 v.7	20070627	Product data sheet	-	BC640_BCP53_BCX53 v.6
BC640_BCP53_BCX53 v.6	20060313	Product data sheet	-	BC636_638_640 v.5
				BCP51_52_53 v.5
				BCX51_52_53 v.4
BC636_638_640 v.5	20041011	Product specification	-	BC636_638_640 v.4
BCP51_52_53 v.5	20030206	Product specification	-	BCP51_52_53 v.4

80 V, 1 A PNP medium power transistors

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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80 V, 1 A PNP medium power transistors

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80 V, 1 A PNP medium power transistors

15. Contents

1	Product profile 1
1.1	General description 1
1.2	Features and benefits1
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 3
4	Marking 3
5	Limiting values 4
6	Thermal characteristics 6
7	Characteristics 12
8	Test information 14
8.1	Quality information 14
9	Package outline 14
10	Packing information 15
11	Soldering 16
12	Revision history 19
13	Legal information 20
13.1	Data sheet status 20
13.2	Definitions 20
13.3	Disclaimers 20
13.4	Trademarks 21
14	Contact information 21
15	Contents 22

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